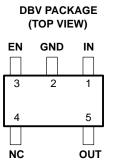
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- 50-mA Low-Dropout Regulator
- Fixed Output Voltage Options: 5 V, 3.8 V, 3.3 V, 3.2 V, and 3 V
- Dropout Typically 120 mV at 50 mA
- Thermal Protection
- Less Than 1-μA Quiescent Current in Shutdown
- -40°C to 125°C Operating Junction Temperature Range
- 5-Pin SOT-23 Package
- ESD Protection Verified to 1.5 kV Human Body Model (HBM) per MIL-STD-883C



NC - No internal connection

## description

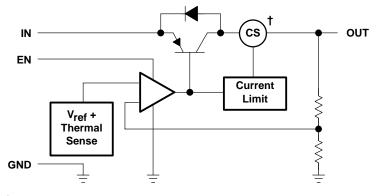
The TPS760xx is a 50 mA, low dropout (LDO) voltage regulator designed specifically for battery-powered applications. A proprietary BiCMOS fabrication process allows the TPS760xx to provide outstanding performance in all specifications critical to battery-powered operation.

The TPS760xx is available in a space-saving SOT-23 package and operates over a junction temperature range of  $-40^{\circ}$ C to  $125^{\circ}$ C.

| AVAILABLE OPTIONS |         |         |              |        |  |  |
|-------------------|---------|---------|--------------|--------|--|--|
| Тj                | VOLTAGE | PACKAGE | PART NUMBER  | SYMBOL |  |  |
| –40°C to 125°C    | 3 V     | SOT-23  | TPS76030DBVR | PAGI   |  |  |
|                   | 3.2 V   |         | TPS76032DBVR | PAOI   |  |  |
|                   | 3.3 V   |         | TPS76033DBVR | PAHI   |  |  |
|                   | 3.8 V   |         | TPS76038DBVR | PAJI   |  |  |
|                   | 5 V     |         | TPS76050DBVR | PANI   |  |  |

NOTE: The DBV package is available taped and reeled only.

## functional block diagram



<sup>†</sup>Current sense



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## **Terminal Functions**

| TERMINAL |     | I/O | DESCRIPTION              |  |  |  |
|----------|-----|-----|--------------------------|--|--|--|
| NAME     | NO. | 1/0 | DESCRIPTION              |  |  |  |
| EN       | 3   | I   | Enable input             |  |  |  |
| GND      | 2   |     | Ground                   |  |  |  |
| IN       | 1   | Ι   | Input voltage            |  |  |  |
| NC       | 4   |     | No connection            |  |  |  |
| OUT      | 5   | 0   | Regulated output voltage |  |  |  |

## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

| Input voltage range, VI <sup>‡</sup>                 | –0.3 V to 16 V               |
|--|------------------------------|
| Voltage range at EN                                  |                              |
| Peak output current                                  | internally limited           |
| Continuous total dissipation                         | See Dissipation Rating Table |
| Operating junction temperature range, T <sub>J</sub> | –40°C to 150°C               |
| Storage temperature range, T <sub>stg</sub>          | –65°C to 150°C               |
| ESD rating, HBM                                      | 1.5 kV                       |

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

<sup>‡</sup> All voltages are with respect to device GND pin.

#### DISSIPATION RATING TABLE

| BOARD   | PACKAGE | $R_{\theta}$ JC | $R_{\theta JA}$ | DERATING FACTOR<br>ABOVE T <sub>A</sub> = 25°C | T <sub>A</sub> ≤ 25°C<br>POWER RATING | T <sub>A</sub> = 70°C<br>POWER RATING | T <sub>A</sub> = 85°C<br>POWER RATING |
|---------|---------|-----------------|-----------------|--|---------------------------------------|---------------------------------------|---------------------------------------|
| Low K§  | DBV     | 65.8 °C/W       | 259 °C/W        | 3.9 mW/°C                                      | 386 mW                                | 212 mW                                | 154 mW                                |
| High K¶ | DBV     | 65.8 °C/W       | 180 °C/W        | 5.6 mW/°C                                      | 555 mW                                | 305 mW                                | 222 mW                                |

§ The JEDEC Low K (1s) board design used to derive this data was a 3 inch x 3 inch, two layer board with 2 ounce copper traces on top of the board.
¶ The JEDEC High K (2s2p) board design used to derive this data was a 3 inch x 3 inch, multilayer board with 1 ounce internal power and ground planes and 2 ounce copper traces on top and bottom of the board.

## recommended operating conditions

|                                    |          | MIN | NOM MAX | UNIT |
|------------------------------------|----------|-----|---------|------|
|                                    | TPS76030 | 3.2 | 16      |      |
|                                    | TPS76032 | 3.4 | 16      |      |
| Input voltage, VI                  | TPS76033 | 3.5 | 16      | V    |
|                                    | TPS76038 | 4   | 16      |      |
|                                    | TPS76050 | 5.2 | 16      |      |
| Continuous output current, I       | C        | 0   | 50      | mA   |
| Operating junction temperature, TJ |          |     | 125     | °C   |



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|                                 | PARAMETER            |  | TEST CONDITIONS  | MIN  | TYP  | MAX  | UNIT  |
|---------------------------------|----------------------|--|--|------|------|------|-------|
|                                 |                      |  | $T_J = 25^{\circ}C$  | 2.96 | 3    | 3.04 |       |
|                                 |                      | TPS76030   | $T_J = 25^{\circ}C$ , 1 mA < I <sub>O</sub> < 50 mA                        | 2.92 |      | 3.04 | V     |
|                                 |                      |  | 1 mA < I <sub>O</sub> < 50 mA  | 2.91 |      | 3.07 |       |
|                                 |                      |  | $T_J = 25^{\circ}C$  | 3.16 | 3.2  | 3.24 |       |
|                                 |                      | TPS76032   | $T_J = 25^{\circ}C$ , 1 mA < I <sub>O</sub> < 50 mA                        | 3.13 |      | 3.24 | V     |
|                                 |                      |  | 1 mA < I <sub>O</sub> < 50 mA  | 3.1  |      | 3.3  | 1     |
|                                 |                      |  | $T_J = 25^{\circ}C$  | 3.26 | 3.3  | 3.34 |       |
| VO                              | Output voltage       | TPS76033   | $T_J = 25^{\circ}C$ , 1 mA < I <sub>O</sub> < 50 mA                        | 3.23 |      | 3.34 | V     |
|                                 |                      |  | 1 mA < I <sub>O</sub> < 50 mA  | 3.2  |      | 3.4  |       |
|                                 |                      |  | $T_J = 25^{\circ}C$  | 3.76 | 3.8  | 3.84 |       |
|                                 |                      | TPS76038   | $T_J = 25^{\circ}C$ , 1 mA < I <sub>O</sub> < 50 mA                        | 3.73 |      | 3.84 | V     |
|                                 |                      |  | 1 mA < I <sub>O</sub> < 50 mA  | 3.7  |      | 3.9  |       |
|                                 |                      |  | $T_J = 25^{\circ}C$  | 4.95 | 5    | 5.05 |       |
|                                 |                      | TPS76050   | $T_J = 25^{\circ}C$ , 1 mA < I <sub>O</sub> < 50 mA                        | 4.91 |      | 5.05 | V     |
|                                 |                      |  | 1 mA < I <sub>O</sub> < 50 mA  | 4.89 |      | 5.1  |       |
| I(standby)                      | Standby current      |  | EN = 0 V   |      |      | 1    | μΑ    |
|                                 |                      |  | $I_{O} = 0 \text{ mA}, 	 T_{J} = 25^{\circ}\text{C}$                       |      | 90   | 115  |       |
|                                 |                      |  | I <sub>O</sub> = 0 mA  |      |      | 130  |       |
|                                 |                      |  | IO = 1 mA, TJ = 25°C   |      | 100  | 130  |       |
|                                 |                      |  | $I_{O} = 1 \text{ mA}$   |      |      | 170  |       |
| Quiescent current (GND current) | GND current)         | $I_{O} = 10 \text{ mA}, \qquad T_{J} = 25^{\circ}\text{C}$ |  | 190  | 215  | μA   |       |
|                                 |                      | I <sub>O</sub> = 10 mA                                     |  |      | 260  |      |       |
|                                 |                      | $I_{O} = 50 \text{ mA}, \qquad T_{J} = 25^{\circ}\text{C}$ |  | 850  | 1100 |      |       |
|                                 |                      |  | I <sub>O</sub> = 50 mA   |      |      | 1200 |       |
|                                 |                      | TPS76030   | $4 V < V_{I} < 16$ , $I_{O} = 1 \text{ mA}$                                |      | 3    | 10   |       |
|                                 |                      | TPS76032   | 4.2 V < VI < 16, IO = 1 mA   |      | 3    | 10   |       |
|                                 | Input regulation     | TPS76033   | $4.3 V < V_{I} < 16$ , $I_{O} = 1 \text{ mA}$                              |      | 3    | 10   | mV    |
|                                 |                      | TPS76038   | $4.8 \text{ V} < \text{V}_{\text{I}} < 16$ , $I_{\text{O}} = 1 \text{ mA}$ |      | 3    | 10   |       |
|                                 |                      | TPS76050   | $6 V < V_{\rm I} < 16$ , $I_{\rm O} = 1 \text{ mA}$                        |      | 3    | 10   | 1     |
| Vn                              | Output noise voltag  | e  | BW = 300 Hz to 50 kHz, $C_0 = 10 \mu F$ , $T_J = 25^{\circ}C$              |      | 190  |      | μVrms |
|                                 | Ripple rejection     |  | f = 1 kHz, C <sub>0</sub> = 10 μF, T <sub>J</sub> = 25°C                   |      | 63   |      | dB    |
|                                 |                      |  | $I_O = 0 \text{ mA } T_J = 25^{\circ}C$                                    |      | 1    | 3    |       |
|                                 |                      |  | I <sub>O</sub> = 0 mA  |      |      | 5    |       |
|                                 |                      |  | IO = 1 mA, TJ = 25°C   |      | 7    | 10   |       |
|                                 |                      |  | I <sub>O</sub> = 1 mA  |      |      | 15   |       |
| Dropout voltage                 |                      |  | $I_{O} = 10 \text{ mA}, \qquad T_{J} = 25^{\circ}\text{C}$                 |      | 40   | 60   | mV    |
|                                 |                      |  | I <sub>O</sub> = 10 mA   |      |      | 90   | 1     |
|                                 |                      |  | $I_O = 50 \text{ mA}$ $T_J = 25^{\circ}C$                                  |      | 120  | 150  | 1     |
|                                 |                      |  | I <sub>O</sub> = 50 mA   |      |      | 180  | 1     |
|                                 | Peak output curren   | t/current limit  |  | 100  | 125  | 135  | mA    |
|                                 | High level enable ir | iput   |  | 2    |      |      | V     |
|                                 | Low level enable in  |  |  |      |      | 0.8  | V     |
|                                 |                      |  | EN = 0 V   | -1   | 0    | 1    | μA    |
| tı –                            | Input current (EN)   |  | EN = VI  |      | 2.5  | 5    | μΑ    |

# electrical characteristics over recommended operating free-air temperature range, $V_I = V_{O(nom)} + 1 V$ , $I_O = 1 mA$ , EN = $V_I$ , $C_O = 2.2 \mu F$ (unless otherwise noted)



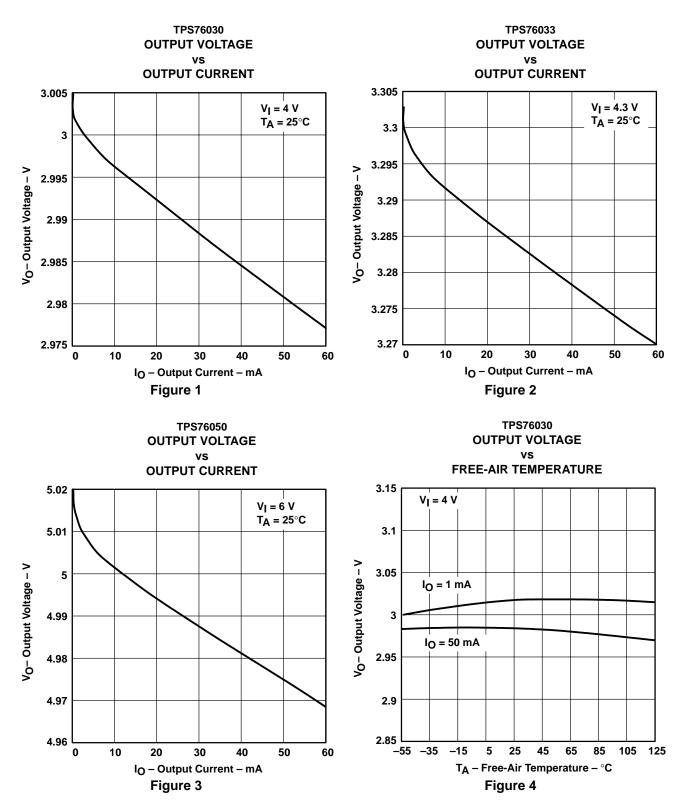
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# **Table of Graphs**

|                |                         |                         | FIGURE  |
|----------------|-------------------------|-------------------------|---------|
| V              |                         | vs Output current       | 1, 2, 3 |
| Vo             | Output voltage          | vs Free-air temperature | 4, 5, 6 |
|                | Ground current          | vs Free-air temperature | 7, 8, 9 |
|                | Output noise            | vs Frequency            | 10      |
| Z <sub>0</sub> | Output impedance        | vs Frequency            | 11      |
| VDO            | Dropout voltage         | vs Free-air temperature | 12      |
|                | Line transient response |                         | 13, 15  |
|                | Load transient response |                         | 14, 16  |

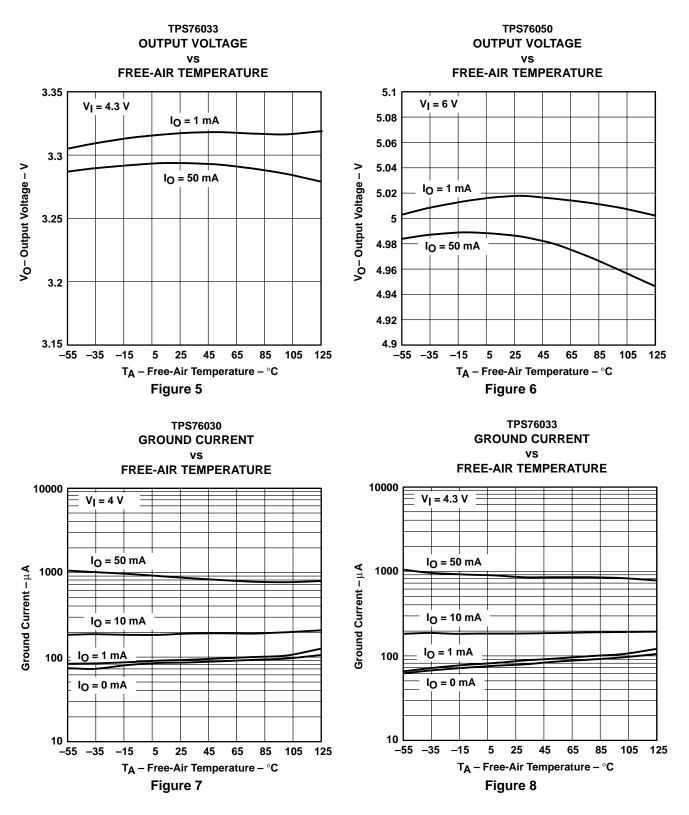


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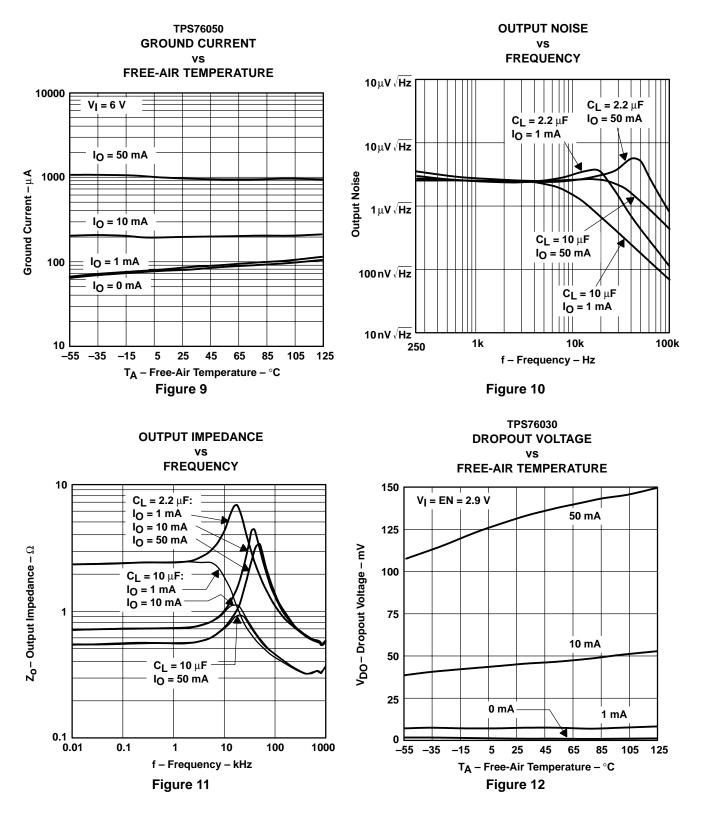


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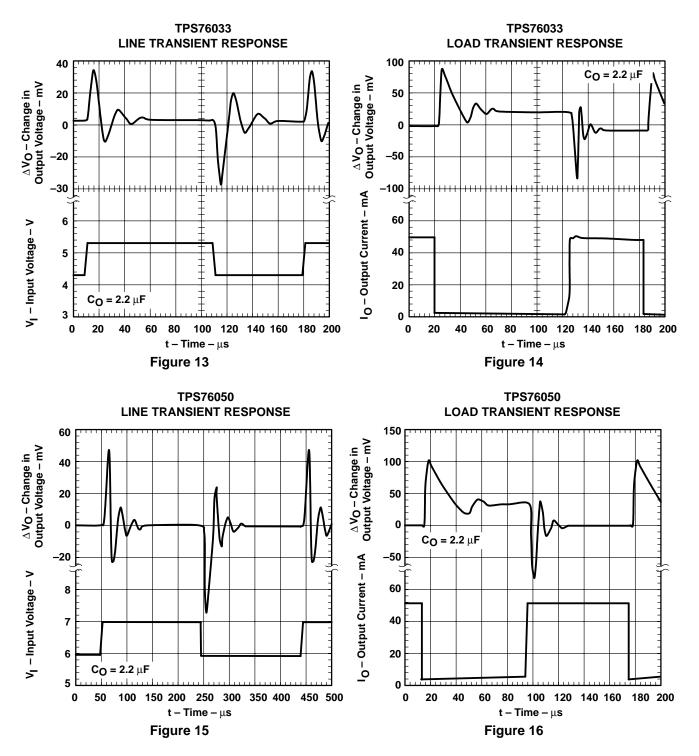


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## **APPLICATION INFORMATION**

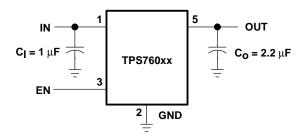


Figure 17. TPS760xx Typical Application

#### over current protection

The over current protection circuit forces the TPS760xx into a constant current output mode when the load is excessive or the output is shorted to ground. Normal operation resumes when the fault condition is removed. An overload or short circuit may also activate the over temperature protection if the fault condition persists.

#### over temperature protection

The thermal protection system shuts the TPS760xx down when the junction temperature exceeds 160°C. The device recovers and operates normally when the temperature drops below 155°C.

## input capacitor

A 0.047  $\mu$ F or larger ceramic decoupling capacitor with short leads connected between IN and GND is recommended. The decoupling capacitor may be omitted if there is a 1  $\mu$ F or larger electrolytic capacitor connected between IN and GND and located reasonably close to the TPS760xx. However, the small ceramic device is desirable even when the larger capacitor is present, if there is a lot of high frequency noise present in the system.

## output capacitor

Like all low dropout regulators, the TPS760xx requires an output capacitor connected between OUT and GND to stabilize the internal control loop. The minimum recommended capacitance value is 2.2  $\mu$ F and the ESR (equivalent series resistance) must be between 0.1  $\Omega$  and 20  $\Omega$ . Capacitor values of 2.5- $\mu$ F or larger are acceptable, provided the ESR is less than 20  $\Omega$ . Solid tantalum electrolytic, aluminum electrolytic, and multilayer ceramic capacitors are all suitable, provided they meet the requirements described above. Most of the commercially available 2.2- $\mu$ F surface-mount solid-tantalum capacitors, including devices from Sprague, Kemet, and Nichicon, meet the ESR requirements stated above. Multilayer ceramic capacitors should have minimum values of 2.5  $\mu$ F over the full operating temperature range of the equipment.

## enable (EN)

A logic zero on the enable input shuts the TPS760xx off and reduces the supply current to less than 1  $\mu$ A. Pulling the enable input high causes normal operation to resume. If the enable feature is not used, EN should be connected to IN to keep the regulator on all of the time. The EN input must not be left floating.

## reverse current path

The power transistor used in the TPS760xx has an inherent diode connected between IN and OUT as shown in the functional block diagram. This diode conducts current from the OUT terminal to the IN terminal whenever IN is lower than OUT by a diode drop. This condition does not damage the TPS760xx, provided the current is limited to 100 mA.

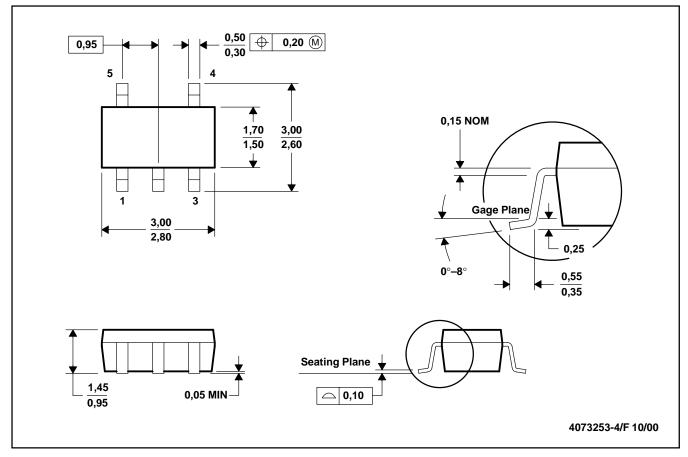


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**MECHANICAL DATA** 

## DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
- D. Falls within JEDEC MO-178



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